

2N5089

### **2N5089 Information**



Part Number	2N5089	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single	
Description	TRANS NPN 25V 0.05A TO92	
Package	TO-226-3, TO-92-3 (TO-226AA)	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



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# **Certified Quality**

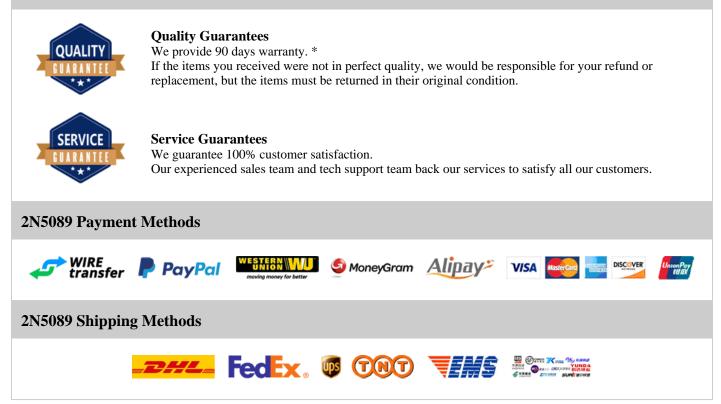
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# **2N5089 Specifications**

Manufacturer Part Number2N5089ManufacturerON SemiconductorCategoryDiscrete Semiconductor ProductsTransistor - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)SomAVoltage - Collector Emitter Breakdown (Max)SomA (CBBO)Current - Collector Cutoff (Max)SomA (CBBO)Current - Collector Cutoff (Max)SonA (CBBO)De Current Gain (hFE) (Min) @ Ic, Vce400 @ 100µA, 5VPower - Max625mWPoquency - TransitionSoMHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226.3, TO-92.3 (TO-226AA)Supplier Device PackageTO-92.3		
CategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Lc) (Max)50mAVoltage - Collector Emitter Breakdown (Max)25VVcc Saturation (Max) @ Ib, Ic50mAV @ ImA, 10mACurrent - Collector Cutoff (Max)50nA (ICBO)DC current Gain (hFE) (Min) @ Ic, Vce400 @ 100µA, 5VPower - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226A, TO-226AA)Supplier Device PackageTO-226Supplier Device PackageTO-92-3	Manufacturer Part Number	2N5089
Transistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)50mAVoltage - Collector Emitter Breakdown (Max)25VVce Saturation (Max) @ Ib, Ic500mV @ 1mA, 10mACurrent - Collector Cutoff (Max)50nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce400 @ 100µA, 5VPower - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226A, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Manufacturer	ON Semiconductor
Package   TO-226-3, TO-92-3 (TO-226AA)     Series   -     Transistor Type   NPN     Current - Collector (Ic) (Max)   50mA     Voltage - Collector Emitter Breakdown (Max)   25V     Vce Saturation (Max) @ Ib, Ic   500mV @ 1mA, 10mA     Current - Collector Cutoff (Max)   50nA (ICBO)     DC Current Gain (hFE) (Min) @ Ic, Vce   400 @ 100µA, 5V     Power - Max   625mW     Frequency - Transition   50MHz     Operating Temperature   -55°C ~ 150°C (TJ)     Mounting Type   Through Hole     Package / Case   TO-226-3, TO-92-3 (TO-226AA)     Supplier Device Package   TO-92-3	Category	Discrete Semiconductor Products
Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)50mAVoltage - Collector Emitter Breakdown (Max)25VVce Saturation (Max) @ Ib, Ic500mV @ 1mA, 10mACurrent - Collector Cutoff (Max)50nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce400 @ 100µA, 5VPower - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3		Transistors - Bipolar (BJT) - Single
Transistor TypeNPNCurrent - Collector (Lo) (Max)50mAVoltage - Collector Emitter Breakdown (Max)25VVce Saturation (Max) @ Ib, Ic500mV @ 1mA, 10mACurrent - Collector Cutoff (Max)50nA (ICBO)DC Current Gain (hFE) (Min @ Ic, Vce400 @ 100µA, 5VPower - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Package	TO-226-3, TO-92-3 (TO-226AA)
Current - Collector (Ic) (Max)50mAVoltage - Collector Emitter Breakdown (Max)25VVce Saturation (Max) @ Ib, Ic500mV @ 1mA, 10mACurrent - Collector Cutoff (Max)50nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce400 @ 100µA, 5VPower - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Series	-
Voltage - Collector Emitter Breakdown (Max)25VVce Saturation (Max) @ Ib, Ic500mV @ 1mA, 10mACurrent - Collector Cutoff (Max)50nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce400 @ 100µA, 5VPower - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Transistor Type	NPN
Yee Saturation (Max) @ Ib, Ic   500mV @ 1mA, 10mA     Current - Collector Cutoff (Max)   50nA (ICBO)     DC Current Gain (hFE) (Min) @ Ic, Vce   400 @ 100μA, 5V     Power - Max   625mW     Frequency - Transition   50MHz     Operating Temperature   -55°C ~ 150°C (TJ)     Mounting Type   Through Hole     Package / Case   TO-226-3, TO-92-3 (TO-226AA)     Supplier Device Package   TO-92-3	Current - Collector (Ic) (Max)	50mA
Current - Collector Cutoff (Max)50nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce400 @ 100µA, 5VPower - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Voltage - Collector Emitter Breakdown (Max)	25V
DC Current Gain (hFE) (Min) @ Ic, Vce 400 @ 100µA, 5V   Power - Max 625mW   Frequency - Transition 50MHz   Operating Temperature -55°C ~ 150°C (TJ)   Mounting Type Through Hole   Package / Case TO-226-3, TO-92-3 (TO-226AA)   Supplier Device Package TO-92-3	Vce Saturation (Max) @ Ib, Ic	500mV @ 1mA, 10mA
Power - Max625mWFrequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Current - Collector Cutoff (Max)	50nA (ICBO)
Frequency - Transition50MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	DC Current Gain (hFE) (Min) @ Ic, Vce	400 @ 100µA, 5V
Operating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Power - Max	625mW
Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Frequency - Transition	50MHz
Package / CaseTO-226-3, TO-92-3 (TO-226AA)Supplier Device PackageTO-92-3	Operating Temperature	-55°C ~ 150°C (TJ)
Supplier Device Package TO-92-3	Mounting Type	Through Hole
	Package / Case	TO-226-3, TO-92-3 (TO-226AA)
Report errors?	Supplier Device Package	TO-92-3
		Report errors?

#### **2N5089 Guarantees**



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